

## SMBYT01

### STATIC ELECTRICAL CHARACTERISTICS

| Symbol   | Test Conditions           |                    | Min. | Typ. | Max. | Unit          |
|----------|---------------------------|--------------------|------|------|------|---------------|
| $V_F$ *  | $T_j = 25^\circ\text{C}$  | $I_F = 1\text{ A}$ |      |      | 1.5  | V             |
|          | $T_j = 100^\circ\text{C}$ |                    |      | 1.05 | 1.4  |               |
| $I_R$ ** | $T_j = 25^\circ\text{C}$  | $V_R = V_{RRM}$    |      |      | 10   | $\mu\text{A}$ |
|          | $T_j = 100^\circ\text{C}$ |                    |      | 0.1  | 0.3  | $\text{mA}$   |

Pulse test : \*  $t_p = 380\text{ }\mu\text{s}$ ,  $\delta < 2\%$

\*\*  $t_p = 5\text{ ms}$ ,  $\delta < 2\%$

### RECOVERY CHARACTERISTICS

| Symbol | Test Conditions          |                                            | Min.                                 | Typ. | Max. | Unit |
|--------|--------------------------|--------------------------------------------|--------------------------------------|------|------|------|
| trr    | $T_j = 25^\circ\text{C}$ | $I_F = 0.5\text{ A}$<br>$I_R = 1\text{ A}$ | $I_{rr} = 0.25\text{ A}$             |      | 25   | ns   |
|        |                          | $I_F = 1\text{ A}$<br>$V_R = 30\text{ V}$  | $di_F/dt = -15\text{ A}/\mu\text{s}$ |      | 60   |      |

### TURN-OFF SWITCHING CHARACTERISTICS (Without serie inductance)

| Symbol    | Test Conditions           |                                                          | Min. | Typ. | Max. | Unit |
|-----------|---------------------------|----------------------------------------------------------|------|------|------|------|
| $t_{IRM}$ | $V_{CC} = 200\text{ V}$   | $I_F = 1\text{ A}$<br>$L_p \leq 0.05\text{ }\mu\text{H}$ |      | 35   | 50   | ns   |
| $I_{RM}$  | $T_j = 100^\circ\text{C}$ | $di_F/dt = -50\text{ A}/\mu\text{s}$                     |      | 1.5  | 2    | A    |

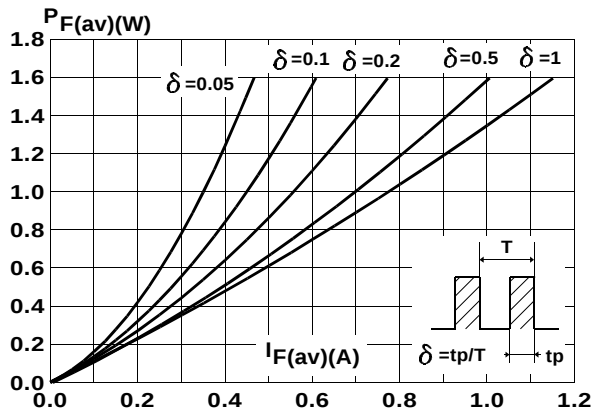
To evaluate the conduction losses use the following equation :

$$P = 1.1 \times I_{F(AV)} + 0.25 \times I_{F(RMS)}^2$$

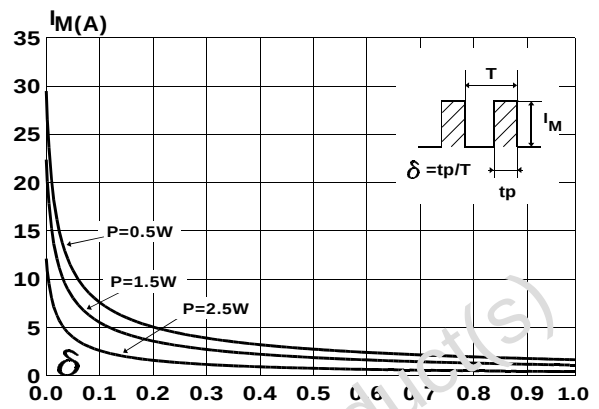
|             |     |
|-------------|-----|
| Voltage (V) | 400 |
| Marking     | B4  |

Laser marking  
Logo indicates cathode

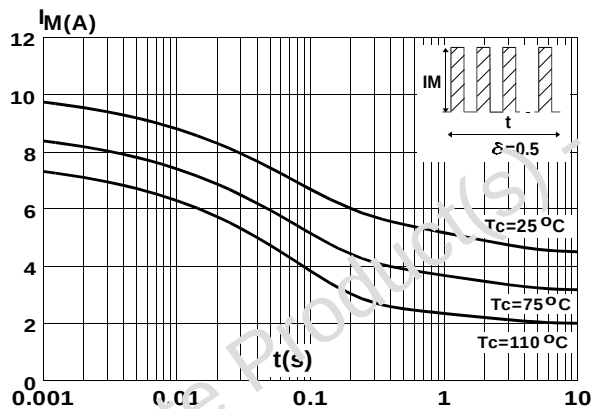
**Fig. 1:** Low frequency power losses versus average current.



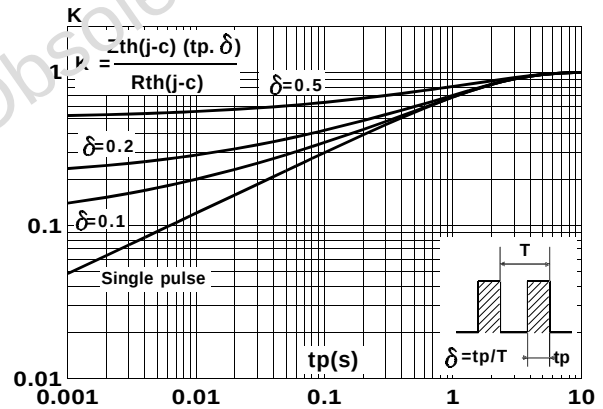
**Fig. 2:** Peak current versus form factor.



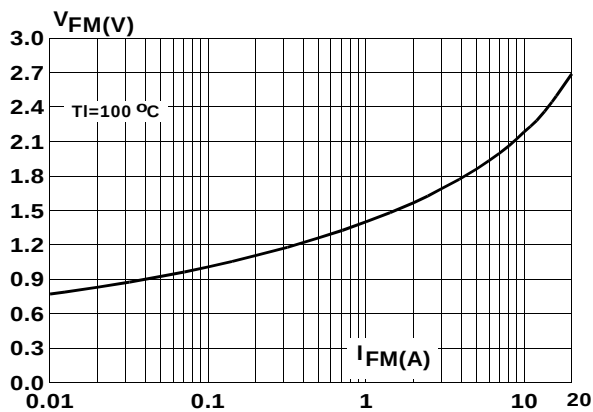
**Fig. 3:** Non repetitive surge peak forward current versus overload duration.



**Fig. 4:** Relative variation of thermal impedance junction to lead versus pulse duration.



**Fig. 5:** Voltage drop versus forward current. (Maximum values)



**Fig. 6:** Average current versus ambient temperature. (duty cycle : 0.5)

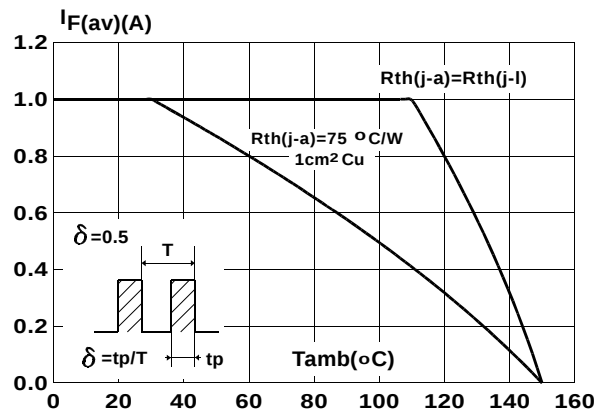


Fig. 7: Recovery time versus  $di_F/dt$ .

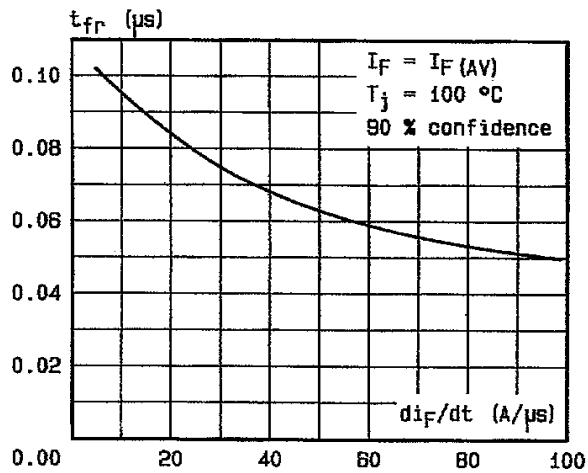


Fig. 9: Peak reverse current versus  $di_F/dt$ .

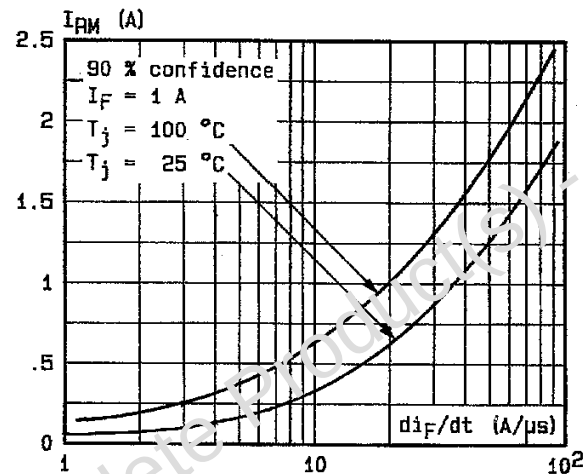


Fig. 11: Dynamic parameters versus junction temperature.

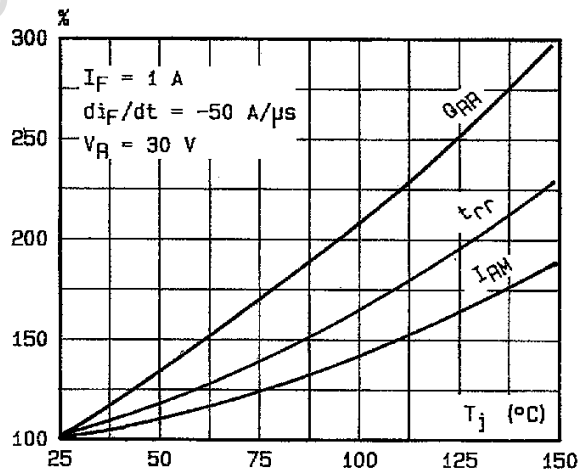


Fig. 8: Peak forward voltage versus  $di_F/dt$ .

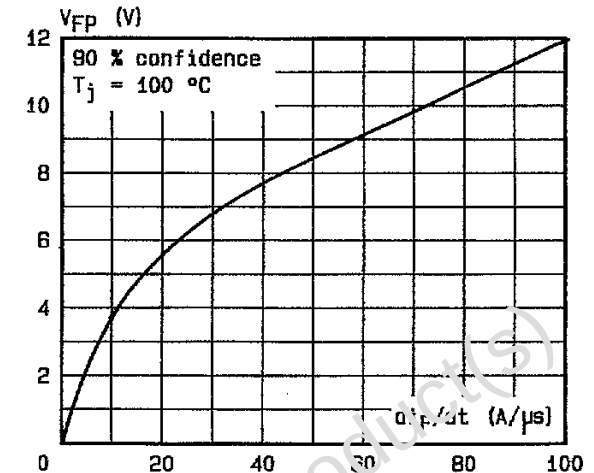


Fig. 10: Recovery charge versus  $di_F/dt$ . (typical values)

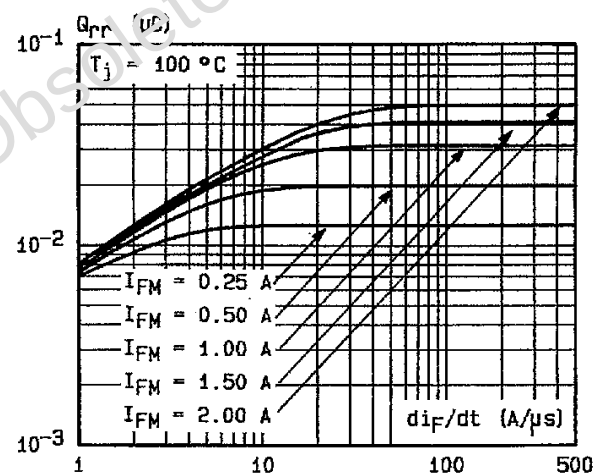
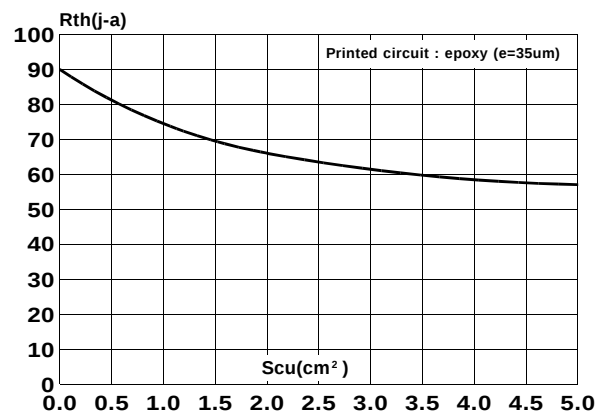


Fig. 12: Thermal resistance junction to ambient versus copper surface under each lead.



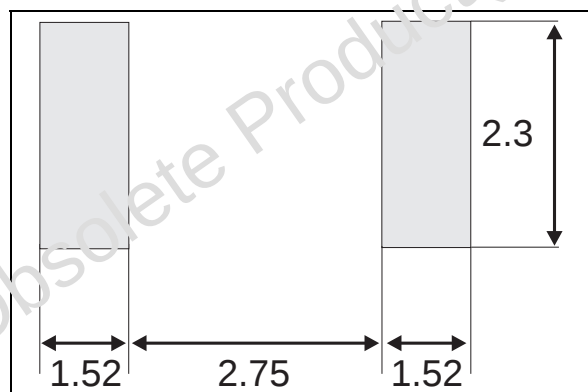
# PACKAGE MECHANICAL DATA

## SMB (Plastic)

| REF. | DIMENSIONS  |      |        |       |
|------|-------------|------|--------|-------|
|      | Millimeters |      | Inches |       |
|      | Min.        | Max. | Min.   | Max.  |
| A1   | 1.90        | 2.45 | 0.075  | 0.096 |
| A2   | 0.05        | 0.20 | 0.002  | 0.008 |
| b    | 1.95        | 2.20 | 0.077  | 0.087 |
| c    | 0.15        | 0.41 | 0.006  | 0.016 |
| E    | 5.10        | 5.60 | 0.201  | 0.220 |
| E1   | 4.05        | 4.60 | 0.159  | 0.181 |
| D    | 3.30        | 3.95 | 0.130  | 0.156 |
| L    | 0.75        | 1.50 | 0.030  | 0.063 |

## FOOTPRINT DIMENSIONS (in millimeters)

### SMB (Plastic)



- Laser marking
- Weight = 0.12 g.
- Logo indicates cathode

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